TROPHY SERIES
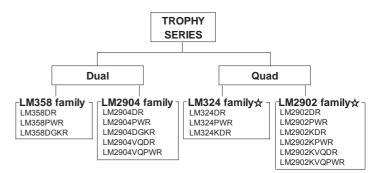
Universal Standard Ground Sense Op-Amp.

LM358 family, LM324 family, LM2904 family, LM2902 family

Pb Free
ROHM Electronic Components

● Description

The Universal Standard family LM358/324 and LM2904/2902 monolithic ICs integrate two independent op-amp circuits and phase compensation capacitors on a single chip, feature high gain and low power consumption, and possess an operating voltage range between 3[V] and 32[V] (single power supply.)

TROPHY SERIES

Dual	Quad

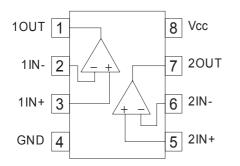| LM358 family	LM2904 family	LM324 family☆	LM2902 family☆
LM358DR	LM2904DR	LM324DR	LM2902DR
LM358PWR	LM2904PWR	LM324PWR	LM2902PWR
LM358DGKR	LM2904DGKR	LM324KDR	LM2902KDR
	LM2904VQDR		LM2902KPWR
	LM2904VQPWR		LM2902KVQDR
			LM2902KVQPWR

☆Under development

● Characteristics

1) Operating temperature range
   Commercial Grade
   LM358/324 family: 0[℃] to +70[℃]
   Extended Industrial Grade
   LM2904/2902 family: -40[℃] to +125[℃]
2) Wide operating voltage range
   +3[V] to +32[V] (single supply)
   ±1.5[V] to ±16[V] (dual supply)

3) Low supply current
4) Common-mode input voltage range, including ground
5) Differential input voltage range equal to maximum rated supply voltage
6) High large signal voltage gain
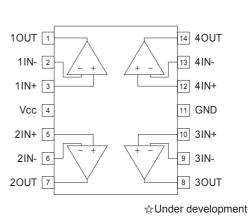7) Wide output voltage range

● Pin Assignment

☆Under development

SOIC8	TSSOP8	MSOP8/VSSOP8	SOIC14	TSSOP14
LM358DR	LM358PWR	LM358DGKR	LM324DR	LM324PWR
LM2904DR	LM2904PWR	LM2904DGKR	LM324KDR	LM2902PWR
LM2904VQDR	LM2904VQPWR		LM2902DR	LM2902KPWR
			LM2902KDR	LM2902KVQPWR
			LM2902KVQDR	

● Absolute Maximum Ratings (Ta=25[℃])

Parameter	Symbol	Rating						Unit
		LM358 family	LM324 family ☆	LM2904 family	LM2902 family ☆	LM2904V family	LM2902V family ☆	
Supply Voltage	Vcc-GND	+32		+26		+32		V
Operating Temperature Range	Topr	0 to +70		-40 to +125				℃
Storage Temperature Range	Tstg	-65 to +150						℃
Input Common-mode Voltage	VICM	-0.3 to +32		-0.3 to +26		-0.3 to +32		V
Maximum Junction Temperature	Tjmax	150						℃

☆Under development

● Electric Characteristics

○LM358,LM324 family (Unless otherwise specified, Vcc=+5[V])

Parameter	Symbol	Temperature range	Limit						Unit	Condition	Fig.No
			LM358 family			LM324 family ☆					
			Min.	Typ.	Max.	Min.	Typ.	Max.			
Input Offset Voltage (*1)	VIO	25℃	—	3	7	—	3	7	mV	VO=1.4[V] VIC=VICR(min) Vcc=5[V] to 30[V]	2
		Full range	—	—	9	—	—	9			
Input Offset Voltage Drift	αVIO	—	—	7	—	—	—	—	μV/℃	—	—
Input Offset Current (*1)	IIO	25℃	—	2	50	—	2	50	nA	VO=1.4[V]	2
		Full range	—	—	150	—	—	150			
Input Offset Current Drift	αIIO	—	—	10	—	—	—	—	pA/℃	—	—
Input Bias Current (*1)	IIB	25℃	—	20	250	—	20	250	nA	VO=1.4[V]	2
		Full range	—	—	500	—	—	500			
Input Common-mode Voltage Range	VICR	25℃	0	—	Vcc-1.5	—	—	Vcc-1.5	V	Vcc=5[V] to 30[V]	2
		Full range	0	—	Vcc-2.0	—	—	Vcc-2.0			
High Level Output Voltage	VOH	25℃	Vcc-1.5	—	—	Vcc-1.5	—	—	V	RL≧2[kΩ]	3
		Full range	27	28	—	27	28	—		Vcc=30[V],RL≧10[kΩ]	
Low Level Output Voltage	VOL	Full range	—	5	20	—	5	20	mV	RL≦10[kΩ]	2
Large Signal Voltage Gain	AVD	25℃	25	100	—	25	100	—	V/mV	Vcc=15[V] VO=1[V] to 11[V] RL≧2[kΩ]	2
Common-mode Rejection Ratio	CMRR	25℃	65	80	—	65	80	—	dB	Vcc=5[V] to 30[V], VIC=VICR(min)	2
Supply-Voltage rejection ratio	KSVR	25℃	65	100	—	65	100	—	dB	Vcc=5[V] to 30[V]	2
Cross-talk Attenuation	VO1/VO2	25℃	—	120	—	—	120	—	dB	f=1[kHz] to 20[kHz]	5
Output Current (*2) Source		25℃	20	30	—	20	30	—	mA	Vcc=15[V],VO=0[V] VID=1[V]	3
		Full range	10	—	—	10	—	—			
Sink		25℃	10	20	—	10	20	—	mA	Vcc=15[V],VO=0[V] VID=-1[V]	
		Full range	2	—	—	2	—	—			
		25℃	12	30	—	12	30	—	μA	VO=200[mV],VID=-1[V]	
Supply Current (All Amps)	ICC	Full range	—	0.7	1.2	—	0.7	1.2	mA	VO=2.5[V],No Load	3
		Full range	—	1	2	—	1.4	3		Vcc=30[V],VO=0.5[V] No Load	
Slew Rate at Unity-Gain	SR	25℃	—	0.3	—	—	0.5	—	V/μs	RL=1[MΩ],CL=30[pF] VI=±10[V] Vcc=15[V],GND=-15[V] (reference to Fig1)	3
Unity Gain Bandwidth	B1	25℃	—	0.7	—	—	1.2	—	MHz	RL=1[MΩ],CL=20[pF] Vcc=15[V],GND=-15[V] (reference to Fig1)	3
Equivalent Input Noise Voltage	Vn	25℃	—	40	—	—	35	—	nV/$\sqrt{Hz}$	Vcc=15[V],GND=-15[V] RS=100[Ω],VI=0[V] f=1[kHz](reference to Fig2)	3

(*1) Absolute value

☆Under development

(*2) Under high temperature, consider the power dissipation of IC when selecting the output current.
When the output terminal is continuously shorted, the output current reduces the temperature inside the IC by flushing.

◯LM2904,LM2902 family (Unless otherwise specified, Vcc=+5[V])

Parameter	Symbol	Temperature range	LM2904 family Min.	LM2904 family Typ.	LM2904 family Max.	LM2902 family☆ Min.	LM2902 family☆ Typ.	LM2902 family☆ Max.	Unit	Condition	Fig.No
Input Offset Voltage (*3)	VIO	25℃	—	3	7	—	3	7	mV	VO=1.4[V],VIC=VICR(min) Vcc=5[V] to MAX(*8)	2
		Full range	—	—	10	—	—	10			
Input Offset Voltage Drift	αVIO	—	—	7	—	—	7	—	μV/℃	—	—
Input Offset Current (*3) LM2904 LM2902 (*5)	IIO	25℃	—	2	50	—	2	50	nA	VO=1.4[V]	2
		Full range	—	—	300	—	—	300			
Input Offset Current (*3) LM2904V LM2902V (*5)		25℃	—	2	50	—	2	50			
		Full range	—	—	150	—	—	150			
Input Offset Current Drift	αIIO	—	—	10	—	—	10	—	pA/℃	—	—
Input Bias Current (*3)	IIB	25℃	—	20	250	—	20	250	nA	VO=1.4[V]	2
		Full range	—	—	500	—	—	500			
Input Common-mode Voltage Range	VICR	25℃	—	—	Vcc-1.5	—	—	Vcc-1.5	V	Vcc=5[V] to MAX(*8)	2
		Full range	—	—	Vcc-2.0	—	—	Vcc-2.0			
High Level Output Voltage	VOH	25℃	Vcc-1.5	—	—	Vcc-1.5	—	—	V	RL≧10[kΩ]	3
High Level Output Voltage LM2904 LM2902 (*5)		Full range	23	24	—	23	24	—		Vcc=MAX(*8),RL≧10[kΩ]	
High Level Output Voltage LM2904V LM2902V (*5)		Full range	27	28	—	27	—	—		Vcc=MAX(*8),RL≧10[kΩ]	
Low Level Output Voltage	VOL	Full range	—	5	20	—	5	20	mV	RL≦10[kΩ]	3
Large Signal Voltage Gain	AVD	25℃	25	100	—	25	100	—	V/mV	Vcc=15[V],VO=1[V] to 11[V] RL≧2[kΩ]	2
Common-mode Rejection Ratio LM2904 LM2902 (*5)	CMRR	25℃	50	80	—	50	80	—	dB	Vcc=5[V] to MAX(*8) VIC=VICR(min)	2
Common-mode Rejection Ratio LM2904V LM2902V (*5)		25℃	65	80	—	60	80	—	dB		
Supply Voltage Rejection Ratio LM2904 LM2904V M2902 (*5)	KSVR	25℃	65	100	—	50	100	—	dB	Vcc=5[V] to MAX(*8)	2
Supply Voltage Rejection Ratio LM2902V (*5)			—	—	—	60	100	—			
Cross-talk Attenuation	VO1/VO2	25℃	—	120	—	—	120	—	dB	f=1[kHz] to 20[kHz]	5
Output Current (*4) Source	Source	25℃	20	30	—	20	30	60	mA	Vcc=15[V],VO=0[V] VID=1[V]	3
		Full range	10	—	—	10	—	—			
Output Current (*4) Sink	Sink	25℃	10	20	—	10	20	—	mA	Vcc=15[V],VO=0[V] VID=-1[V]	
		Full range	2	—	—	2	—	—			
Output Current LM2904 LM2902 (*5)	Io	25℃	—	30	—	—	30	—	μA	VO=200[mV],VID=-1[V]	
Output Current LM2904V LM2902V (*5)		25℃	12	40	—	12	40	—	μA		
Supply Current (All Amps)	ICC	Full range	—	0.7	1.2	—	0.7	1.2	mA	VO=2.5[V],No Load	3
		Full range	—	1	2	—	1.4	3		Vcc=MAX(*8),VO=0.5[V] No Load	
Slew Rate at Unity Gain	SR	25℃	—	0.3	—	—	0.5	—	V/μs	RL=1[MΩ],CL=30[pF], VI=±10[V] Vcc=15[V],GND=-15[V] (reference to Fig1)	3
Unity-Gain Bandwidth	B1	25℃	—	0.7	—	—	1.2	—	MHz	RL=1[MΩ],CL=20[pF] Vcc=15[V],GND=-15[V] (reference to Fig1)	3
Equivalent Input Noise Voltage	Vn	25℃	—	40	—	—	35	—	nV/√Hz	Vcc=15[V],GND=-15[V] RS=100[Ω]VI=0[V] f=1[kHz], (reference to Fig2)	3

(*3) Absolute value

☆Under development

(*4) Under high temperature, consider the power dissipation of the IC when selecting the output current.
When the output terminal is continuously shorted the output current is reduced to lower the temperature inside the IC.

(*5) The maximum supply voltage is 26V for the LM2904DR, LM2904PW, LM2904PWR, and LM2904DQKR
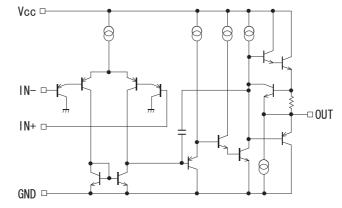The maximum supply voltage is 32V for the LM2904VQDR and LM2904VQPWR

●Circuit Diagram

Fig.1 Circuit Diagram (each Op-Amp)

●Measurement circuit 1 NULL Method measurement condition

Vcc,GND,EK,VICR Unit:[V]

Measurement item	VF	S1	S2	S3	LM358/LM324 family				LM2904/LM2902 family				Calculation
					Vcc	GND	EK	VICR	Vcc	GND	EK	VICR	
Input Offset Voltage	VF1	ON	ON	OFF	5 to 30	0	- 1.4	0	5 to 30	0	- 1.4	0	1
Input Offset Current	VF2	OFF	OFF	OFF	5	0	- 1.4	0	5	0	- 1.4	0	2
Input Bias Current	VF3	OFF	ON	OFF	5	0	- 1.4	0	5	0	- 1.4	0	3
	VF4	ON	OFF		5	0	- 1.4	0	5	0	- 1.4	0	
Large Signal Voltage Gain	VF5	ON	ON	ON	15	0	- 1.4	0	15	0	- 1.4	0	4
	VF6				15	0	-11.4	0	15	0	-11.4	0	
Common-mode Rejection Ratio	VF7	ON	ON	OFF	5	0	- 1.4	0	5	0	- 1.4	0	5
	VF8				5	0	- 1.4	3.5	5	0	- 1.4	3.5	
Supply Voltage Rejection Ratio	VF9	ON	ON	OFF	5	0	- 1.4	0	5	0	- 1.4	0	6
	VF10				30	0	- 1.4	0	30	0	- 1.4	0	

－Calculation－

1.Input Offset Voltage (VIO)

$$Vio = \frac{|VF1|}{1+Rf/Rs} \ [V]$$

2. Input offset current (IIO)

$$Iio = \frac{|VF2-VF1|}{Ri(1+Rf/Rs)} \ [A]$$

3.Input Bias Current (IIB)

$$Ib = \frac{|VF4-VF3|}{2\times Ri(1+Rf/Rs)} \ [A]$$

4.Large Signal Voltage Gain (AVD)

$$AV = 20\times Log \frac{10\times(1+Rf/Rs)}{|VF6-VF5|} \ [dB]$$

5.Common-mode rejection ratio (CMRR)

$$CMRR = 20\times Log \frac{3.5\times(1+Rf/Rs)}{|VF8-VF7|} \ [dB]$$

6.Supply Voltage rejection ratio (KSVR)

$$PSRR = 20\times Log \frac{\triangle Vcc\times(1+Rf/Rs)}{VF10-VF9} \ [dB]$$

$$\triangle Vcc=25V$$
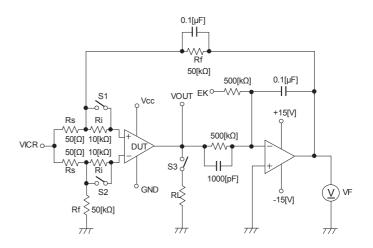

Fig.2 Measurement Circuit 1 (each Op-Amp)

● Measurement Circuit 2: Switch Condition

SW No.	SW 1	SW 2	SW 3	SW 4	SW 5	SW 6	SW 7	SW 8	SW 9	SW 10	SW 11	SW 12	SW 13	SW 14	SW 15
Supply Current	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	OFF
High Level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF
Low Level Output Voltage	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON	OFF
Output Source Current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	ON
Output Sink Current	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF	ON
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF	OFF
Unity-gain Bandwidth Product	OFF	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF
Equivalent Input Noise Voltage	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF	OFF

Fig.3 Measurement Circuit 2 (each Op-Amp)

Fig.4 Slew Rate Input Waveform

$$SR = \Delta V / \Delta t$$

● Measurement Circuit 3: Cross-talk Attenuation

$$VO1/VO2 = 20 \times \log \frac{100 \times VOUT1}{VOUT2}$$

Fig.5 Measurement Circuit 3
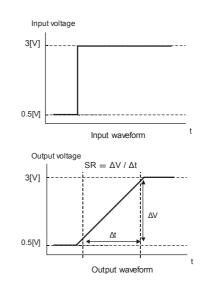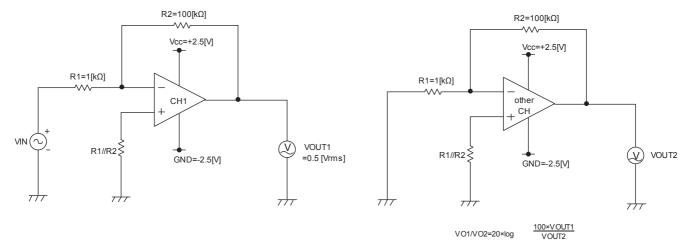
●Description of Electrical Characteristics

Described below are descriptions of the relevant electrical terms
Please note that item names, symbols and their meaning may differ form those on another manufacturer's documents.

1. Absolute maximum ratings

The absolute maximum ratings are values that should never be exceeded, since doing so may result in deterioration of characteristics or damage to the part itself as well as peripheral components.

1.1 Power supply voltage (Vcc/GND)
Expresses the maximum voltage that can be supplied between the positive and negative power supply terminals without causing deterioration of characteristics or destruction of the internal circuitry.

1.2 Differential input voltage (VID)
Indicates the maximum voltage that can be supplied between the non-inverting and inverting terminals without damaging the IC.

1.3 Input common-mode voltage range (VICR)
Signifies the maximum voltage that can be supplied to the non-inverting and inverting terminals without causing deterioration of the electrical characteristics or damage to the IC itself. Normal operation is not guaranteed within the input common-mode voltage range of the maximum ratings – use within the input common-mode voltage range of the electric characteristics instead.

1.4 Operating temperature range and storage temperature range (Topr, Tstg)
The operating temperature range indicates the temperature range within which the IC can operate. The higher the ambient temperature, the lower the power consumption of the IC. The storage temperature range denotes the range of temperatures the IC can be stored under without causing excessive deterioration of the electrical characteristics.

1.5 Power dissipation (Pd)
Indicates the power that can be consumed by a specific mounted board at ambient temperature (25℃). For packaged products, Pd is determined by the maximum junction temperature and the thermal resistance.

2. Electric characteristics

2.1 Input offset voltage (VIO)
Signifies the voltage difference between the non-inverting and inverting terminals. It can be thought of as the input voltage difference required for setting the output voltage to 0V.

2.2 Input offset voltage drift (α VIO)
Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.

2.3 Input offset current (IIO)
Indicates the difference of the input bias current between the non-inverting and inverting terminals.

2.4 Input offset current drift (α IIO)
Signifies the ratio of the input offset current fluctuation to the ambient temperature fluctuation.

2.5 Input bias current (IIB)
Denotes the current that flows into or out of the input terminal, it is defined by the average of the input bias current at the non-inverting terminal and the input bias current at the inverting terminal.

2.6 Circuit current (ICC)
Indicates the current of the IC itself that flows under specific conditions and during no-load steady state.

2.7 High level output voltage/low level output voltage (VOH/VOL)
Signifying the voltage range that can be output by under specific load conditions, it is in general divided into high level output voltage and low level output voltage. High level output voltage indicates the upper limit of the output voltage, while low level output voltage the lower limit.

2.8 Differential voltage amplification (AVD)
The amplifying rate (gain) of the output voltage against the voltage difference between non-inverting and inverting terminals, it is (normally) the amplifying rate (gain) with respect to DC voltage.
AVD = (output voltage fluctuation) / (input offset fluctuation)

2.9 Input common-mode voltage range (VICR)
Indicates the input voltage range under which the IC operates normally.

2.10 Common-mode rejection ratio (CMRR)
Signifies the ratio of fluctuation of the input offset voltage when the in-phase input voltage is changed (DC fluctuation).
CMRR = (change in input common-mode voltage) / (input offset fluctuation)

2.11 Power supply rejection ratio (KSVR)
Denotes the ratio of fluctuation of the input offset voltage when the supply voltage is changed (DC fluctuation).
KSVR = (change in power supply voltage) / (input offset fluctuation)

2.12 Output source current/ output sink current (IOH/IOL)
The maximum current that can be output under specific output conditions, it is divided into output source current and output sink current. The output source current indicates the current flowing out of IC, and the output sink current the current flowing into the IC.

2.13 Cross talk attenuation (VO1/VO2)
Expresses the amount of fluctuation in the input offset voltage or output voltage with respect to the change in the output voltage of a driven channel.
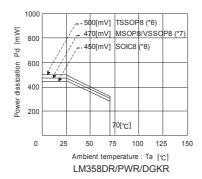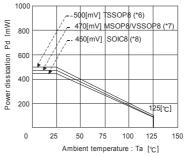
2.14 Slew rate at unity gain (SR)
Indicates the time fluctuation ratio of the output voltage when an input step signal is supplied.

2.15 Unity gain bandwidth (B1)
The product of the specified signal frequency and the gain of the op-amp at such frequency, it gives the approximate value of the frequency where the gain of the op-amp is 1 (maximum frequency, unity gain frequency).

● Derating Curves

LM358DR/PWR/DGKR

LM2904DR/PWR/DGKR/VQDR/VQPWR

Power Dissipation

Package	Pd[W]	θ ja [℃/W]
SOIC8 (*8)	450	3.6
TSSOP8 (*6)	500	4.0
MSOP8/VSSOP8 (*7)	470	3.76

θ ja = (Tj-Ta)/Pd[℃/W]

Fig.6 Derating Curves

● Precautions

1) Unused circuits
   When there are unused circuits, it is recommended that they be connected as in Figure 7, setting the non-inverting input terminal to a potential within the in-phase input voltage range (VICR).

2) Input terminal voltage
   Applying GND + 32V to the input terminal is possible without causing deterioration of the electrical characteristics or destruction, irrespective of the supply voltage. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

3) Power supply (single / dual)
   The op-amp operates when the voltage is applied between Vcc and GND. Therefore, the single supply op-amp can be used as a dual supply op-amp as well.

Fig.7 Disable circuit example

4) Power dissipation (Pd)
   Using the unit in excess of the rated power dissipation may cause deterioration in electrical characteristics due to the rise of chip temperature, including reduced current capability. Therefore, please take into consideration the power dissipation (Pd) under the actual operating conditions and apply a sufficient margin in thermal design. Refer to the thermal derating curves for more information.

5) Short-circuits between pins and erroneous mounting
   Incorrect mounting may damage the IC. In addition, the presence of foreign substances between the outputs, the output and the power supply, or the output and GND may also result in IC destruction.

6) Operation in a strong electromagnetic field
   Operation in a strong electromagnetic field may cause malfunctions.

7) Radiation
   This IC is not designed to withstand radiation.

8) IC handing
   Applying mechanical stress to the IC by deflecting or bending the board may cause fluctuation of the electrical characteristics due to piezoelectric (piezo) effects.

9) IC operation
   The output stage of the IC is configured using Class C push-pull circuits. Therefore, when the load resistor is connected to the middle potential of Vcc and GND, crossover distortion occurs at the changeover between discharging and charging of the output current. Connecting a resistor between the output terminal and GND and increasing the bias current for Class A operation will suppress crossover distortion.

10) Board inspection
   Connecting a capacitor to a pin with low impedance may stress the IC. Therefore, discharging the capacitor after every process is recommended. In addition, when attaching and detaching the jig during the inspection phase, ensure that the power is turned OFF before inspection and removal. Furthermore, please take measures against ESD in the assembly process as well as during transportation and storage.

11) Output capacitor
   Discharge of the external output capacitor to Vcc is possible via internal parasitic elements when Vcc is shorted to GND, causing damage to the internal circuitry due to thermal stress. Therefore, when using this IC in circuits where oscillation due to output capacitive load does not occur, such as in voltage comparators, use an output capacitor with a capacitance less than 0.1 μ F.
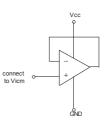
●Dimensions

| SOIC8 | TSSOP8 | MSOP/VSSOP8 |

| SOIC14 | TSSOP14 |
☆Under development   ☆Under development

●Part Number Explanation

· Specify the product by the part number when placing orders.
· Verify that the entire part number is correct
· Start with the leftmost space without leaving any empty space between characters.

L M 2 9 0 2 K V Q D R

family name
· LM358
· LM324
· LM2904
· LM2902

ESD tolerance applicable
· K   : 2kV
· None : Normal

Operating voltage
· VQ   : 32V
· None : 26V

Package type
· D   : SOIC
· PW   : TSSOP
· DGK : MSOP/VSSOP

R : Reel

Tape	Embossed carrier tape
Quantity	2500pcs
Direction of feed	Pin 1 is at the upper left holding the reel with the left hand while pulling the tape out with the right

Reel   Pin 1   Direction of feed

※Please order in multiples of the minimum package quantity.